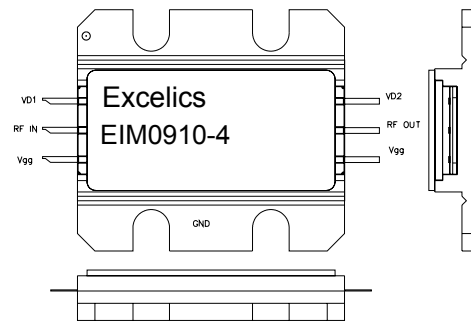


FEATURES

- 9.50– 10.50GHz Operating Frequency Range
- 35.5dBm Output Power at 1dB Compression
- 29.0 dB Typical Power Gain @1dB gain compression
- -45dBc Typical OIM3 @ each tone Pout 22.5dBm
- Non-Hermetic Metal Flange Package

APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems



Caution! ESD sensitive device.

ELECTRICAL CHARACTERISTICS (Tb = 25 °C, 50 ohm, VD1=7V, VD2=10V, Vgg=-5V)

| SYMBOL | PARAMETER/TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------------|---|------|------|------|-------|
| F | Operating Frequency Range | 9.5 | | 10.5 | GHz |
| P1dB | Output Power at 1dB Gain Compression | 34.5 | 35.5 | | dBm |
| G1dB | Gain @1dB gain compression | 26 | 29 | | dB |
| OIMD3 | Output 3 rd Order Intermodulation Distortion @Δf=10MHz, Each Tone Pout 22.5dBm | | -45 | | dBc |
| Input RL | Input Return Loss | | -12 | -8 | dB |
| Output RL | Output Return Loss | | -15 | -10 | dB |
| VD1 | Drain Supply Voltage 1 | | 7 | | V |
| VD2 | Drain Supply Voltage 2 | | 10 | | V |
| I_{DQ1} | Quiescent Drain Current 1 | | 380 | | mA |
| I_{DQ2} | Quiescent Drain Current 2 | | 1800 | 2000 | mA |
| Vgg | Gate Supply Voltage | | -5 | | V |
| Rth | Thermal Resistance | | 3.4 | | °C/W |
| ΔTch | Channel Temperature Rise | | | 80 | °C |

Note: Turn on/off sequence is required:

- to turn on: apply -5V on both Vgg first, then +7V and +10V.
- to turn off: turn +7V and +10V off first, then turn -5V off



EIM0910-4

ISSUED 07/16/2007

9.5-10.5GHz Multi-Stage Power Amplifier

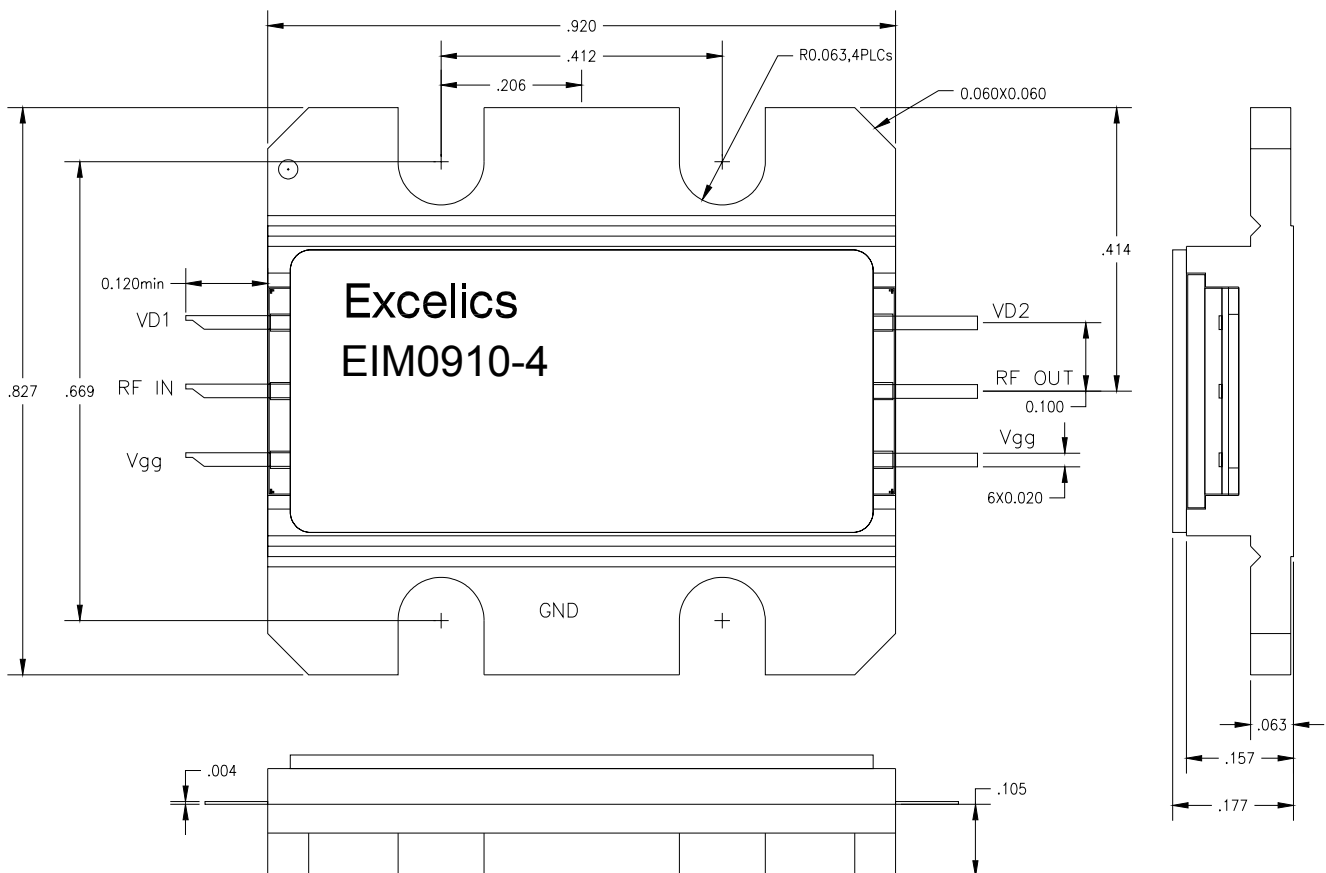
MAXIMUM RATINGS @25°C^{1,2}

| SYMBOL | CHARACTERISTIC | ABSOLUTE | CONTINUOUS ^{1,2} |
|------------------|-------------------------|-----------|---------------------------|
| V _{D1} | Drain Supply Voltage 1 | 12V | 8V |
| V _{D2} | Drain Supply Voltage 2 | 14V | 10V |
| V _{gg} | Gate Supply Voltage | -10V | -6 V |
| I _{gg} | Gate Current | 150mA | 50 mA |
| P _{IN} | Input Power | 17dBm | @ 3dB compression |
| T _{CH} | Channel Temperature | 175°C | 165°C |
| T _{STG} | Storage Temperature | -65/175°C | -65/175°C |
| P _T | Total Power Dissipation | 36.7W | 30.9W |

Notes: 1. Operating the device beyond any of the above rating may reduce MTTF and cause permanent damage.

2. Bias conditions must also satisfy the following equation $V_{dd} \cdot I_{dd} < (T_{CH} - T_b) / R_{TH}$

Package Dimension and Pin Assignment



Dimensions are in inches

Specifications are subject to change without notice.

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EIM0910-4

ISSUED 07/16/2007

9.5-10.5GHz Multi-Stage Power Amplifier

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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